

# Solid Tantalum Chip Capacitors TANTAMOUNT™, Hi-Rel COTS, Ultra-Low ESR, Built-in-Fuse, Conformal Coated Case





#### PERFORMANCE CHARACTERISTICS

www.vishay.com/doc?40209

Operating Temperature: -55 °C to +125 °C (above 85 °C, voltage derating is required)

Capacitance Range: 10 μF to 1500 μF

Capacitance Tolerance: ± 10 %, ± 20 % standard

Voltage Rating: 4 V<sub>DC</sub> to 75 V<sub>DC</sub>

#### **FEATURES**

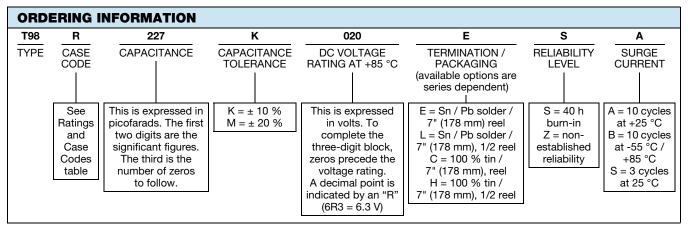
reliability design High reliability screening available



 Surge current testing per MIL-PRF-55365 options available

- Ultra-low ESR
- · Mounting: surface mount
- Terminations: SnPb, standard. 100 % tin available
- Circuit protection for mission or safety critical systems
- Typical fuse activation curve is provided in the FAQ (www.vishav.com/doc?40110)
- Moisture sensitivity level 2a
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

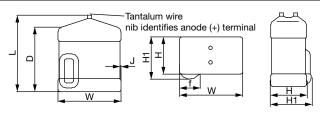
This datasheet provides information about parts that are RoHS-compliant and / or parts that are non RoHS-compliant. For example, parts with lead (Pb) terminations are not RoHS-compliant. Please see the information / tables in this datasheet for details



#### Note

We reserve the right to supply higher voltage ratings and tighter capacitance tolerance capacitors in the same case size. Low ESR solid tantalum chip capacitors allow delta ESR of 1.25 times the datasheet limits after mounting

#### **DIMENSIONS** in inches [millimeters]



CASE CODE	L (MAX.)	w	H1	Н	f (REF.)	D (REF.)	J (MAX.)
V	0.299	0.181 ± 0.016	0.099 max.	0.087 [2.2]	0.079	0.256	0.004
	[7.6]	[4.6 ± 0.4]	[2.5 max.]	max.	[2.0]	[6.5]	[0.1]
E	0.299	0.181 ± 0.016	0.177 ± 0.016	0.165 ± 0.016	0.079	0.256	0.004
	[7.6]	[4.6 ± 0.4]	[4.5 ± 0.4]	[4.2 ± 0.4]	[2.0]	[6.5]	[0.1]
R	0.299	0.246 ± 0.016 / - 0.024	0.162 ± 0.016	0.150 ± 0.016	0.079	0.248	0.004
	[7.6]	[6.2 ± 0.4 / - 0.6]	[4.1 ± 0.4]	[3.8 ± 0.4]	[2.0]	[6.3]	[0.1]
F	0.299	0.246 ± 0.016	0.207 ± 0.016	0.193 ± 0.016	0.079	0.248	0.004
	[7.6]	[6.2 ± 0.4]	[5.3 ± 0.4]	[4.9 ± 0.4]	[2.0]	[6.3]	[0.1]
Z	0.299	0.246 ± 0.016	0.258 ± 0.016	0.244 ± 0.016	0.079	0.248	0.004
	[7.6]	[6.2 ± 0.4]	[6.6 ± 0.4]	[6.2 ± 0.4]	[2.0]	[6.3]	[0.1]
М	0.327	0.268 ± 0.016	0.161 ± 0.016	0.150 ± 0.016	0.079	0.248	0.004
	[8.3]	[6.8 ± 0.4]	[4.1 ± 0.4]	[3.8 ± 0.4]	[2.0]	[6.3]	[0.1]
Н	0.315	0.268 ± 0.016	0.224 ± 0.016	0.213 ± 0.016	0.079	0.264	0.004
	[8.0]	[6.8 ± 0.4]	[5.7 ± 0.4]	[5.4 ± 0.4]	[2.0]	[6.7]	[0.1]

RATING	RATINGS AND CASE CODES									
μF	4 V	6.3 V	10 V	16 V	20 V	25 V	35 <b>V</b>	50 V	63 V	75 <b>V</b>
10										R
22									F	
47							R	Z		
68						R				
100										
150						F				
220				E	R	М				
330			E		F/H <sup>(1)</sup>					
470	V	Е	Е							
680	Е	Е	R							
1000	E/R	R								
1500	R									
2200										

#### Note

<sup>(1)</sup> Preliminary rating. Contact factory for availability



STANDARD F	RATINGS					
CAPACITANCE (µF)	CASE CODE	PART NUMBER (1)	MAX. DCL AT +25 °C (μA)	MAX. DF AT +25 °C 120 Hz (%)	MAX. ESR AT +25 °C 100 kHz (mΩ)	MAX. RIPPLE 100 kHz I <sub>RMS</sub> (A)
		4 V <sub>DC</sub> AT +8	35 °C; 2.7 V <sub>DC</sub> AT +	+125 °C		
470	V	T98V477(1)004(2)(3)(4)	18.8	8	130	1.0
680	Е	T98E687(1)004(2)(3)(4)	27.2	6	125	1.3
1000	E	T98E108(1)004(2)(3)(4)	40.0	8	120	1.3
1000	R	T98R108(1)004(2)(3)(4)	40.0	8	118	1.5
1500	R	T98R158(1)004(2)(3)(4)	60.0	8	115	1.5
		6.3 V <sub>DC</sub> AT	+85 °C; 4 V <sub>DC</sub> AT -	+125 °C		
470	Е	T98E477(1)6R3(2)(3)(4)	29.6	6	130	1.3
680	Е	T98E687(1)6R3(2)(3)(4)	42.8	6	125	1.3
1000	R	T98R108(1)6R3(2)(3)(4)	63.0	8	120	1.4
		10 V <sub>DC</sub> AT	+85 °C; 7 V <sub>DC</sub> AT +	-125 °C		
330	Е	T98E337(1)010(2)(3)(4)	33.0	6	135	1.3
470	Е	T98E477(1)010(2)(3)(4)	47.0	6	128	1.3
680	R	T98R687(1)010(2)(3)(4)	68.0	6	128	1.4
		16 V <sub>DC</sub> AT +	85 °C; 10 V <sub>DC</sub> AT	+125 °C		
220	Е	T98E227(1)016(2)(3)(4)	35.2	8	160	1.2
		20 V <sub>DC</sub> AT +	85 °C; 13 V <sub>DC</sub> AT	+125 °C		
220	R	T98R227(1)020(2)(3)(4)	44.0	8	180	1.2
330	F	T98F337(1)020(2)(3)(4)	66.0	10	200	1.1
330	H <sup>(1)</sup>	T98H337(1)020(2)(3)(4)	66.0	10	200	1.2
		25 V <sub>DC</sub> AT +	85 °C; 17 V <sub>DC</sub> AT	+125 °C		
68	R	T98R686(1)025(2)(3)(4)	17.0	6	200	1.1
150	F	T98F157(1)025(2)(3)(4)	37.5	8	180	1.2
220	М	T98M227M025(2)(3)(4)	55.0	8	200	1.1
		35 V <sub>DC</sub> AT +	85 °C; 23 V <sub>DC</sub> AT	+125 °C		
47	R	T98R476(1)035(2)(3)(4)	16.5	6	200	1.1
			85 °C; 33 V <sub>DC</sub> AT			
47	Z	T98Z476(1)050(2)(3)(4)	23.5	6	245	1.0
00	F		85 °C; 42 V <sub>DC</sub> AT		250	0.0
22	r	T98F226(1)063(2)(3)(4)	13.9 <b>85 °C; 50 V<sub>DC</sub> AT</b>	6 .125 °C	350	0.8
10	R	T98R106(1)075(2)(3)(4)	7.5	+125°C	600	0.6
10	11	13011100(1)013(2)(3)(4)	1.0	U	000	0.0

- Part number definitions:
  - (1) Capacitance tolerance: K, M
  - (2) Termination and packaging: C, E, H, L
  - (3) Reliability level: S, Z
  - (4) Surge current: A, B, S
- (1) Contact factory for availability



POWER DISSIPATION					
CASE CODE	MAXIMUM PERMISSIBLE POWER DISSIPATION AT +25 °C (W) IN FREE AIR				
V	0.140				
E	0.215				
R	0.250				
F	0.250				
Z	0.265				
М	0.250				
Н	0.265				

STANDARD PACKAGING QUANTITY					
CASE CODE	UNITS F	PER REEL			
CASE CODE	7" FULL REEL	7" HALF REEL			
V	TBD				
E	TBD				
R	300	150			
F	250	125			
Z	150	75			
M	200	100			
Н	TBD				

PRODUCT INFORMATION				
Conformal Coated Guide				
Pad Dimensions	www.vishay.com/doc?40150			
Packaging Dimensions				
Moisture Sensitivity (MSL)	www.vishay.com/doc?40135			
SELECTOR GUIDES				
Solid Tantalum Selector Guide	www.vishay.com/doc?49053			
Solid Tantalum Chip Capacitors	www.vishay.com/doc?40091			
FAQ				
Frequently Asked Questions	www.vishay.com/doc?40110			

# **Guide for Conformal Coated Tantalum Capacitors**

#### INTRODUCTION

Tantalum electrolytic capacitors are the preferred choice in applications where volumetric efficiency, stable electrical parameters, high reliability, and long service life are primary considerations. The stability and resistance to elevated temperatures of the tantalum / tantalum oxide / manganese dioxide system make solid tantalum capacitors an appropriate choice for today's surface mount assembly technology.

Vishay Sprague has been a pioneer and leader in this field, producing a large variety of tantalum capacitor types for consumer, industrial, automotive, military, and aerospace electronic applications.

Tantalum is not found in its pure state. Rather, it is commonly found in a number of oxide minerals, often in combination with Columbium ore. This combination is known as "tantalite" when its contents are more than one-half tantalum. Important sources of tantalite include Australia, Brazil, Canada, China, and several African countries. Synthetic tantalite concentrates produced from tin slags in Thailand, Malaysia, and Brazil are also a significant raw material for tantalum production.

Electronic applications, and particularly capacitors, consume the largest share of world tantalum production. Other important applications for tantalum include cutting tools (tantalum carbide), high temperature super alloys, chemical processing equipment, medical implants, and military ordnance.

Vishay Sprague is a major user of tantalum materials in the form of powder and wire for capacitor elements and rod and sheet for high temperature vacuum processing.

#### THE BASICS OF TANTALUM CAPACITORS

Most metals form crystalline oxides which are non-protecting, such as rust on iron or black oxide on copper. A few metals form dense, stable, tightly adhering, electrically insulating oxides. These are the so-called "valve" metals and include titanium, zirconium, niobium, tantalum, hafnium, and aluminum. Only a few of these permit the accurate control of oxide thickness by electrochemical means. Of these, the most valuable for the electronics industry are aluminum and tantalum.

Capacitors are basic to all kinds of electrical equipment, from radios and television sets to missile controls and automobile ignitions. Their function is to store an electrical charge for later use.

Capacitors consist of two conducting surfaces, usually metal plates, whose function is to conduct electricity. They are separated by an insulating material or dielectric. The dielectric used in all tantalum electrolytic capacitors is tantalum pentoxide.

Tantalum pentoxide compound possesses high-dielectric strength and a high-dielectric constant. As capacitors are being manufactured, a film of tantalum pentoxide is applied to their electrodes by means of an electrolytic process. The film is applied in various thicknesses and at various voltages and although transparent to begin with, it takes on different colors as light refracts through it. This coloring occurs on the tantalum electrodes of all types of tantalum capacitors.

Rating for rating, tantalum capacitors tend to have as much as three times better capacitance / volume efficiency than aluminum electrolytic capacitors. An approximation of the capacitance / volume efficiency of other types of capacitors may be inferred from the following table, which shows the dielectric constant ranges of the various materials used in each type. Note that tantalum pentoxide has a dielectric constant of 26, some three times greater than that of aluminum oxide. This, in addition to the fact that extremely thin films can be deposited during the electrolytic process mentioned earlier, makes the tantalum capacitor extremely efficient with respect to the number of microfarads available per unit volume. The capacitance of any capacitor is determined by the surface area of the two conducting plates, the distance between the plates, and the dielectric constant of the insulating material between the plates.

COMPARISON OF CAPACITOR DIELECTRIC CONSTANTS				
DIELECTRIC	e DIELECTRIC CONSTANT			
Air or vacuum	1.0			
Paper	2.0 to 6.0			
Plastic	2.1 to 6.0			
Mineral oil	2.2 to 2.3			
Silicone oil	2.7 to 2.8			
Quartz	3.8 to 4.4			
Glass	4.8 to 8.0			
Porcelain	5.1 to 5.9			
Mica	5.4 to 8.7			
Aluminum oxide	8.4			
Tantalum pentoxide	26			
Ceramic	12 to 400K			

In the tantalum electrolytic capacitor, the distance between the plates is very small since it is only the thickness of the tantalum pentoxide film. As the dielectric constant of the tantalum pentoxide is high, the capacitance of a tantalum capacitor is high if the area of the plates is large:

$$C = \frac{eA}{t}$$

where

C = capacitance

e = dielectric constant

A = surface area of the dielectric

t = thickness of the dielectric

Tantalum capacitors contain either liquid or solid electrolytes. In solid electrolyte capacitors, a dry material (manganese dioxide) forms the cathode plate. A tantalum lead is embedded in or welded to the pellet, which is in turn connected to a termination or lead wire. The drawings show the construction details of the surface mount types of tantalum capacitors shown in this catalog.



### Vishay Sprague

#### SOLID ELECTROLYTE TANTALUM CAPACITORS

Solid electrolyte capacitors contain manganese dioxide, which is formed on the tantalum pentoxide dielectric layer by impregnating the pellet with a solution of manganous nitrate. The pellet is then heated in an oven, and the manganous nitrate is converted to manganese dioxide.

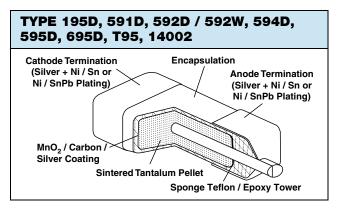
The pellet is next coated with graphite, followed by a layer of metallic silver, which provides a conductive surface between the pellet and the can in which it will be enclosed. After assembly, the capacitors are tested and inspected to assure long life and reliability. It offers excellent reliability and high stability for consumer and commercial electronics with the added feature of low cost.

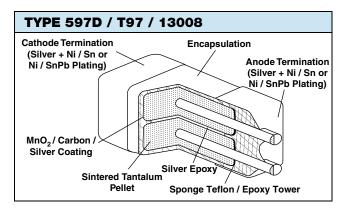
Surface mount designs of "Solid Tantalum" capacitors use lead frames or lead frameless designs as shown in the accompanying drawings.

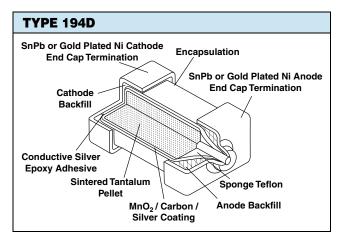
# TANTALUM CAPACITORS FOR ALL DESIGN CONSIDERATIONS

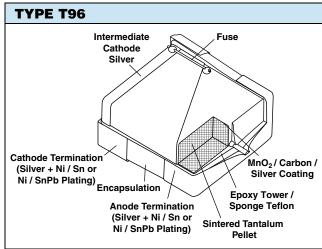
Solid electrolyte designs are the least expensive for a given rating and are used in many applications where their very small size for a given unit of capacitance is of importance. They will typically withstand up to about 10 % of the rated DC working voltage in a reverse direction. Also important are their good low temperature performance characteristics and freedom from corrosive electrolytes.

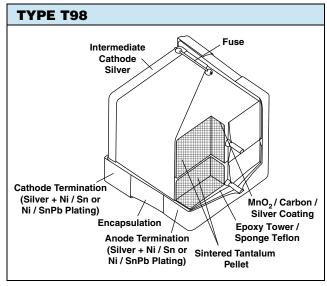
Vishay Sprague patented the original solid electrolyte capacitors and was the first to market them in 1956. Vishay Sprague has the broadest line of tantalum capacitors and has continued its position of leadership in this field. Data sheets covering the various types and styles of Vishay Sprague capacitors for consumer and entertainment electronics, industry, and military applications are available where detailed performance characteristics must be specified.











#### Note

 For all types of conformal coated capacitors, tantalum wire to tantalum pellet attachment method could be either embedded (see images on the left side of the page) or welded (see images on the right side), depending on specific rating



#### **COMMERCIAL PRODUCTS**

SOLID TANTALUM CAPACITORS - CONFORMAL COATED							
SERIES	592W	592D	591D	595D	594D		
PRODUCT IMAGE							
TYPE		Surface mount	TANTAMOUNT™ chip, co	nformal coated			
FEATURES	Low profile, robust design for use in pulsed applications	Low profile, maximum CV	Low profile, low ESR, maximum CV	Maximum CV	Low ESR, maximum CV		
TEMPERATURE RANGE	-55 °C to +125 °C (above 40 °C, voltage deratig is required)	-55 °C to +125 °C (above 85 °C, voltage derating is required)					
CAPACITANCE RANGE	330 μF to 2200 μF	1 μF to 2200 μF	1 μF to 1500 μF	0.1 μF to 1500 μF	1 μF to 1500 μF		
VOLTAGE RANGE	6 V to 10 V	4 V to 50 V	4 V to 50 V	4 V to 50 V	4 V to 50 V		
CAPACITANCE TOLERANCE	± 20 %	± 10 %, ± 20 %	± 10 %, ± 20 %	± 10 %, ± 20 %	± 10 %, ± 20 %		
LEAKAGE CURRENT			0.01 CV or 0.5 μA, v	vhichever is greater			
DISSIPATION FACTOR	14 % to 45 %	4 % to 50 %	4 % to 50 %	4 % to 20 %	4 % to 20 %		
CASE CODES	C, M, X	S, A, B, C, D, R, M, X	A, B, C, D, R, M	T, S, A, B, C, D, G, M, R	B, C, D, R		
TERMINATION	100 % matte tin	100 %	matte tin standard, tin /	lead and gold plated av	vailable		

SOLID TANTALUM CAPACITORS - CONFORMAL COATED								
SERIES	597D	695D	195D	194D				
PRODUCT IMAGE								
TYPE		Tantamount™ chip	o, conformal coated					
FEATURES	Ultra low ESR, maximum CV, multi-anode	Pad compatible with 194D and CWR06	US and European case sizes	Industrial version of CWR06 / CWR16				
TEMPERATURE RANGE	-55 °C to +125 °C (above 85 °C, voltage derating is required)							
CAPACITANCE RANGE	10 μF to 2200 μF	0.1 μF to 270 μF	0.1 μF to 330 μF	0.1 μF to 330 μF				
VOLTAGE RANGE	4 V to 75 V	4 V to 50 V	2 V to 50 V	4 V to 50 V				
CAPACITANCE TOLERANCE		± 10 %,	± 20 %					
LEAKAGE CURRENT		0.01 CV or 0.5 μA, ν	whichever is greater					
DISSIPATION FACTOR	6 % to 20 %	4 % to 8 %	4 % to 8 %	4 % to 10 %				
CASE CODES	V, D, E, R, F, Z, M, H	A, B, D, E, F, G, H	C, S, V, X, Y, Z, R, A, B, D, E, F, G, H	A, B, C, D, E, F, G, H				
TERMINATION	100 % matte tin standard, tin / lead solder plated available	100 % matte tin / lead and gol	Gold plated standard; tin / lead solder plated and hot solder dipped available					



#### **HIGH RELIABILITY PRODUCTS**

SOLID TANTALUM CAPACITORS - CONFORMAL COATED									
SERIES	CWR06	CWR16	CWR26	13008	14002				
PRODUCT IMAGE									
TYPE		TANTAMOUNT™ chip, conformal coated							
FEATURES	MIL-PRF-55365/4 qualified MIL-PRF-55365/13 MIL-PRF-55365/13 DLA approx				proved				
TEMPERATURE RANGE		-55 °C to +125 °C (a	above 85 °C, voltage	derating is required)					
CAPACITANCE RANGE	0.10 μF to 100 μF	0.33 μF to 330 μF	10 μF to 100 μF	10 μF to 1500 μF	4.7 μF to 680 μF				
VOLTAGE RANGE	4 V to 50 V	4 V to 35 V	15 V to 35 V	4 V to 63 V	4 V to 50 V				
CAPACITANCE TOLERANCE	± 5 %, ± 10 %, ± 20 %	± 5 %, ± 10 %, ± 20 %	± 5 %, ± 10 %, ± 20 %	± 10 %, ± 20 %	± 10 %, ± 20 %				
LEAKAGE CURRENT	0.01 CV or 1.0 μA, whichever is greater 0.01 CV or 0.5 μA, whichever is greater								
DISSIPATION FACTOR	6 % to 10 % 6 % to 10 % 6 % to 12 % 6 % to 20 % 6 % to				6 % to 14 %				
CASE CODES	A, B, C, D, E, F, G, H	A, B, C, D, E, F, G, H	F, G, H	V, E, F, R, Z, D, M, H, N	B, C, D, R				
TERMINATION	Gold plated	l; tin / lead; tin / lead s	solder fused	Tin /	lead				

SOLID TANTALUM CA	SOLID TANTALUM CAPACITORS - CONFORMAL COATED						
SERIES	T95	T96	T97	T98			
PRODUCT IMAGE							
TYPE		TANTAMOUNT™ chip, Hi-Re	el COTS, conformal coated				
FEATURES	High reliability	High reliability, built in fuse	High reliability, ultra low ESR, multi-anode	High reliability, ultra low ESR, built in fuse, multi-anode			
TEMPERATURE RANGE	-55	°C to +125 °C (above 85 °	C, voltage derating is requir	red)			
CAPACITANCE RANGE	0.15 μF to 680 μF	10 μF to 680 μF	10 μF to 2200 μF	10 μF to 1500 μF			
VOLTAGE RANGE	4 V to 50 V	4 V to 50 V	4 V to 75 V	4 V to 75 V			
CAPACITANCE TOLERANCE	± 10 %, ± 20 %	± 10 %, ± 20 %	± 10 %, ± 20 %	± 10 %, ± 20 %			
LEAKAGE CURRENT	0.01 CV or 0.5 μA, whichever is greater						
DISSIPATION FACTOR	4 % to 14 %	6 % to 14 %	6 % to 20 %	6 % to 10 %			
CASE CODES	A, B, C, D, R, S, V, X, Y, Z	R	V, E, F, R, Z, D, M, H, N	V, E, F, R, Z, M, H			
TERMINATION		100 % matte	tin, tin / lead				

Vishay Sprague



- · Metric dimensions will govern. Dimensions in inches are rounded and for reference only
- (1) A<sub>0</sub>, B<sub>0</sub>, K<sub>0</sub>, are determined by the maximum dimensions to the ends of the terminals extending from the component body and / or the body dimensions of the component. The clearance between the ends of the terminals or body of the component to the sides and depth of the cavity (A<sub>0</sub>, B<sub>0</sub>, K<sub>0</sub>) must be within 0.002" (0.05 mm) minimum and 0.020" (0.50 mm) maximum. The clearance allowed must also prevent rotation of the component within the cavity of not more than 20°
- (2) Tape with components shall pass around radius "R" without damage. The minimum trailer length may require additional length to provide "R" minimum for 12 mm embossed tape for reels with hub diameters approaching N minimum
- (3) This dimension is the flat area from the edge of the sprocket hole to either outward deformation of the carrier tape between the embossed cavities or to the edge of the cavity whichever is less
- (4) This dimension is the flat area from the edge of the carrier tape opposite the sprocket holes to either the outward deformation of the carrier tape between the embossed cavity or to the edge of the cavity whichever is less
- (5) The embossed hole location shall be measured from the sprocket hole controlling the location of the embossment. Dimensions of embossment location shall be applied independent of each other
- (6) B<sub>1</sub> dimension is a reference dimension tape feeder clearance only





CARRIER TAPE DIMENSIONS in inches [millimeters]							
TAPE WIDTH	W	D <sub>0</sub>	P <sub>2</sub>	F	E <sub>1</sub>	E <sub>2 min.</sub>	
8 mm	0.315 + 0.012 / - 0.004 [8.0 + 0.3 / - 0.1]	0.059 + 0.004 / - 0 [1.5 + 0.1 / - 0]	0.078 ± 0.0019 [2.0 ± 0.05]	0.14 ± 0.0019 [3.5 ± 0.05]	0.324 ± 0.004 [1.75 ± 0.1]	0.246 [6.25]	
12 mm	0.479 + 0.012 / - 0.004 [12.0 + 0.3 / - 0.1]			0.216 ± 0.0019 [5.5 ± 0.05]		0.403 [10.25]	
16 mm	0.635 + 0.012 / - 0.004 [16.0 + 0.3 / - 0.1]		$[1.5 + 0.1 / - 0]$ $0.078 \pm 0.004$	0.295 ± 0.004 [7.5 ± 0.1]		0.570 [14.25]	
24 mm	0.945 ± 0.012 [24.0 ± 0.3]		[2.0 ± 0.1]	0.453 ± 0.004 [11.5 ± 0.1]		0.876 [22.25]	

CARRIER T	APE DIMENSIONS in	inches [millimeters	[5]		
ТҮРЕ	CASE CODE	TAPE WIDTH W IN mm	P <sub>1</sub>	K <sub>0 max.</sub>	B <sub>1 max</sub> .
	A	8	0.157 ± 0.004	0.058 [1.47]	0.149 [3.78]
	В	12	[4.0 ± 0.10]	0.088 [2.23]	0.166 [4.21]
	С	12		0.088 [2.23]	0.290 [7.36]
	D	12	0.315 ± 0.004	0.088 [2.23]	0.300 [7.62]
592D 592W	М	16	[8.0 ± 0.10]	0.091 [2.30]	0.311 [7.90]
591D	R	12		0.088 [2.23]	0.296 [7.52]
	S	8	0.157 ± 0.004	0.058 [1.47]	0.139 [3.53]
	Т	12	[4.0 ± 0.10]	0.088 [2.23]	0.166 [4.21]
	Х	24	0.472 ± 0.004 [12.0 ± 0.10]	0.011 [2.72]	0.594 [15.1]
	A	8	0.157 ± 0.004	0.063 [1.60]	0.152 [3.86]
	В	12	$[4.0 \pm 0.10]$	0.088 [2.23]	0.166 [4.21]
	С	12	0.315 ± 0.004 [8.0 ± 0.10]	0.118 [2.97]	0.290 [7.36]
	D	12		0.119 [3.02]	0.296 [7.52]
	G	12		0.111 [2.83]	0.234 [5.95]
595D	Н	12		0.098 [2.50]	0.232 [5.90]
594D	М	12	0.157 ± 0.004 [4.0 ± 0.10]	0.085 [2.15]	0.152 [3.85]
	R	12	0.315 ± 0.004 [8.0 ± 0.10]	0.148 [3.78]	0.296 [7.52]
	S	8	0.157 ± 0.004	0.058 [1.47]	0.149 [3.78]
	Т	8	$[4.0 \pm 0.10]$	0.054 [1.37]	0.093 [2.36]
	A	8		0.058 [1.47]	0.139 [3.53]
	В	12	0.157 ± 0.004	0.059 [1.50]	0.189 [4.80]
695D	D	12	$[4.0 \pm 0.10]$	0.063 [1.62]	0.191 [4.85]
	Е	12	1	0.074 [1.88]	0.239 [6.07]
	F	12	0.315 ± 0.004 [8.0 ± 0.10]	0.075 [1.93]	0.259 [6.58]
	G	12	0.157 ± 0.004 [4.0 ± 0.10]	0.109 [2.77]	0.301 [7.65]
	Н	16	0.315 ± 0.004 [8.0 ± 0.10]	0.124 [3.15]	0.31 [7.87]



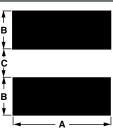
# Vishay Sprague

		TAPE WIDTH			
TYPE	CASE CODE	W IN mm	P <sub>1</sub>	K <sub>0 max</sub> .	B <sub>1 max</sub> .
	A	8		0.058 [1.47]	0.139 [3.53]
	В	12	1	0.058 [1.47]	0.189 [4.80]
	С	8	0.157 ± 0.004	0.054 [1.37]	0.093 [2.36]
			$[4.0 \pm 0.10]$		
	D E	12 12	-	0.067 [1.70] 0.074 [1.88]	0.179 [4.55] 0.239 [6.07]
	<u> </u>	12	0.015 + 0.004	0.074 [1.00]	0.239 [6.07]
	F	12	0.315 ± 0.004 [8.0 ± 0.10]	0.076 [1.93]	0.259 [6.58]
195D	G	12	0.157 ± 0.004 [4.0 ± 0.10]	0.109 [2.77]	0.301 [7.65]
	H <sup>(1)</sup>	12	0.472 ± 0.004 [12.0 ± 0.1]	0.122 [3.11]	0.163 [4.14]
	R	12	0.315 ± 0.004 [8.0 ± 0.10]	0.149 [3.78]	0.296 [7.52]
	S	8		0.058 [1.47]	0.149 [3.78]
	V	8	0.457 0.004	0.060 [1.52]	0.150 [3.80]
	X	12	0.157 ± 0.004	0.069 [1.75]	0.296 [7.52]
	Υ	12	$[4.0 \pm 0.10]$	0.089 [2.26]	0.296 [7.52]
	Z	12	1	0.114 [2.89]	0.288 [7.31]
	A	8		0.069 [1.75]	0.139 [3.53]
	В	12		0.073 [1.85]	0.189 [4.80]
1010	С	12	$0.157 \pm 0.004$	0.069 [1.75]	0.244 [6.20]
194D CWR06	D	12	$[4.0 \pm 0.10]$	0.068 [1.72]	0.191 [4.85]
CWR16	E	12	1	0.074 [1.88]	0.239 [6.07]
CWR26	F	12		0.091 [2.31]	0.262 [6.65]
	G	16	$0.315 \pm 0.004$	0.134 [3.40]	0.289 [7.34]
	Н	16	$[8.0 \pm 0.10]$	0.129 [3.28]	0.319 [8.10]
	D	16	0.317 ± 0.004	0.150 [3.80]	0.313 [7.95]
	E	16	$[8.0 \pm 0.10]$	0.173 [4.40]	0.343 [8.70]
	F	16	[0.0 = 0.10]	0.205 [5.20]	0.309 [7.85]
	H	16	-	0.224 [5.70]	0.313 [7.95]
597D	M	16	$0.476 \pm 0.004$	0.193 [4.90]	0.339 [8.60]
T97	N	16	[12.0 ± 0.1]	0.193 [4.90]	0.323 [8.20]
13008	R	16			
		-	0.317 ± 0.004	0.159 [4.05]	0.313 [7.95]
	V	12	$[8.0 \pm 0.10]$ 0.476 ± 0.004	0.088 [2.23]	0.300 [7.62]
	Z	16	[12.0 ± 0.1]	0.239 [6.06]	0.311 [7.90]
	A	8	0.157 ± 0.004	0.063 [1.60]	0.152 [3.86]
	В	12	$[4.0 \pm 0.10]$	0.088 [2.23]	0.166 [4.21]
	С	12		0.117 [2.97]	0.290 [7.36]
	D	12	$0.317 \pm 0.004$	0.119 [3.02]	0.296 [7.52]
T95	R	12	$[8.0 \pm 0.10]$	0.149 [3.78]	0.296 [7.52]
- <del>-</del>	S	8	]	0.058 [1.47]	0.149 [3.78]
	V	8	0.157 ± 0.004	0.060 [1.52]	0.150 [3.80]
	X	12	$[4.0 \pm 0.10]$	0.069 [1.75]	0.296 [7.52]
	Y	12	<u> </u>	0.089 [2.26]	0.296 [7.52]
	Z	12		0.114 [2.89]	0.288 [7.31]
	В	12	0.157 ± 0.004	0.088 [2.23]	0.166 [4.21]
14002	С	12	$[4.0 \pm 0.10]$	0.117 [2.97]	0.290 [7.36]
14002	D	12	0.317 ± 0.004	0.119 [3.02]	0.296 [7.52]
	R	12	$[8.0 \pm 0.10]$	0.149 [3.78]	0.296 [7.52]
T96	R	16	0.476 ± 0.004 [12.0 ± 0.1]	0.159 [4.05]	0.313 [7.95]
	F	16		0.239 [6.06]	0.311 [7.90]
T98	M	16	$0.476 \pm 0.004$	0.193 [4.90]	0.339 [8.60]
190	Z	16	$[12.0 \pm 0.1]$	0.272 [6.90]	0.307 [7.80]

#### Note

 $^{(1)}\,$  H case only, packaging code T: lengthwise orientation at capacitors in tape

### **PAD DIMENSIONS** in inches [millimeters]

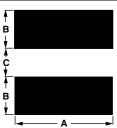


CASE CODE	WIDTH (A)	PAD METALLIZATION (B)	SEPARATION (C)		
592D / W - 591D					
Α	0.075 [1.9]	0.050 [1.3]	0.050 [1.3]		
В	0.118 [3.0]	0.059 [1.5]	0.059 [1.5]		
С	0.136 [3.5]	0.090 [2.3]	0.122 [3.1]		
D	0.180 [4.6]	0.090 [2.3]	0.134 [3.4]		
М	0.050 [0.5]	Anode pad: 0.095 [2.4]	0 120 [2 5]		
IVI	0.256 [6.5]	Cathode pad: 0.067 [1.7]	0.138 [3.5]		
D	0.040 [6.1]	Anode pad: 0.095 [2.4]	0.110 [0.0]		
R	0.240 [6.1]	Cathode pad: 0.067 [1.7]	0.118 [3.0]		
S	0.067 [1.7]	0.032 [0.8]	0.043 [1.1]		
Χ	0.310 [7.9]	0.120 [3.0]	0.360 [9.2]		
595D - 594D		·			
Т	0.059 [1.5]	0.028 [0.7]	0.024 [0.6]		
S	0.067 [1.7]	0.032 [0.8]	0.043 [1.1]		
А	0.083 [2.1]	0.050 [1.3]	0.050 [1.3]		
В	0.118 [3.0]	0.059 [1.5]	0.059 [1.5]		
С	0.136 [3.5]	0.090 [2.3]	0.122 [3.1]		
D	0.180 [4.6]	0.090 [2.3]	0.134 [3.4]		
G	0.156 [4.05]	0.090 [2.3]	0.082 [2.1]		
M	0.110 [2.8]	0.087 [2.2]	0.134 [3.4]		
R	0.248 [6.3]	0.090 [2.3]	0.140 [3.6]		
195D		· ·			
А	0.067 [1.7]	0.043 [1.1]	0.028 [0.7]		
В	0.063 [1.6]	0.047 [1.2]	0.047 [1.2]		
С	0.059 [1.5]	0.031 [0.8]	0.024 [0.6]		
D	0.090 [2.3]	0.055 [1.4]	0.047 [1.2]		
Е	0.090 [2.3]	0.055 [1.4]	0.079 [2.0]		
F	0.140 [3.6]	0.063 [1.6]	0.087 [2.2]		
G	0.110 [2.8]	0.059 [1.5]	0.126 [3.2]		
Н	0.154 [3.9]	0.063 [1.6]	0.140 [3.6]		
N	0.244 [6.2]	0.079 [2.0]	0.118 [3.0]		
R	0.248 [6.3]	0.090 [2.3]	0.140 [3.6]		
S	0.079 [2.0]	0.039 [1.0]	0.039 [1.0]		
V	0.114 [2.9]	0.039 [1.0]	0.039 [1.0]		
Х	0.118 [3.0]	0.067 [1.7]	0.122 [3.1]		
Υ	0.118 [3.0]	0.067 [1.7]	0.122 [3.1]		
Z	0.118 [3.0]	0.067 [1.7]	0.122 [3.1]		



Vishay Sprague

#### **PAD DIMENSIONS** in inches [millimeters]



	A				
CASE CODE	WIDTH (A)	PAD METALLIZATION (B)	SEPARATION (C)		
CWR06 / CWR16 / CWR26 - 194	D - 695D				
А	0.065 [1.6]	0.50 [1.3]	0.040 [1.0]		
В	0.065 [1.6]	0.70 [1.8]	0.055 [1.4]		
С	0.065 [1.6]	0.70 [1.8]	0.120 [3.0]		
D	0.115 [2.9]	0.70 [1.8]	0.070 [1.8]		
E	0.115 [2.9]	0.70 [1.8]	0.120 [3.0]		
F	0.150 [3.8]	0.70 [1.8]	0.140 [3.6]		
G	0.125 [3.2]	0.70 [1.8]	0.170 [4.3]		
Н	0.165 [4.2]	0.90 [2.3]	0.170 [4.3]		
T95					
В	0.120 [3.0]	0.059 [1.5]	0.059 [1.5]		
С	0.136 [3.5]	0.090 [2.3]	0.120 [3.1]		
D	0.180 [4.6]	0.090 [2.3]	0.136 [3.47]		
R	0.248 [6.3]	0.090 [2.3]	0.140 [3.6]		
S	0.080 [2.03]	0.040 [1.02]	0.040 [1.02]		
V	0.114 [2.9]	0.040 [1.02]	0.040 [1.02]		
X, Y, Z	0.114 [2.9]	0.065 [1.65]	0.122 [3.1]		
14002					
В	0.120 [3.0]	0.059 [1.5]	0.059 [1.5]		
С	0.136 [3.5]	0.090 [2.3]	0.120 [3.1]		
D	0.180 [4.6]	0.090 [2.3]	0.136 [3.47]		
R	0.248 [6.3]	0.090 [2.3]	0.140 [3.6]		
T96					
R	0.248 [6.3]	0.090 [2.3]	0.140 [3.6]		
597D - T97 - T98 - 13008					
D, E, V	0.196 [4.9]	0.090 [2.3]	0.140 [3.6]		
F, R, Z	0.260 [6.6]	0.090 [2.3]	0.140 [3.6]		
M, H, N	0.284 [7.2]	0.090 [2.3]	0.140 [3.6]		

8 min max.

Time 25 °C to peak temperature

Vishay Sprague

#### **RECOMMENDED REFLOW PROFILES** Capacitors should withstand reflow profile as per J-STD-020 standard, three cycles. T<sub>C</sub> - 5 °C Max. ramp-up rate = 3 °C/s Max. ramp-down rate = $6 \, ^{\circ}\text{C/s}$ (°C) $T_{s max.}$ Preheat area T<sub>s min.</sub> 25 Time 25 °C to peak TIME (s) **PROFILE FEATURE SnPb EUTECTIC ASSEMBLY LEAD (Pb)-FREE ASSEMBLY** Preheat / soak Temperature min. (T<sub>s min.</sub>) 100 °C 150 °C Temperature max. (T<sub>s max.)</sub> 150 °C 200 °C Time ( $t_s$ ) from ( $T_{s min.}$ to $T_{s max.}$ ) 60 s to 120 s 60 s to 120 s Ramp-up Ramp-up rate (T<sub>L</sub> to T<sub>p</sub>) 3 °C/s max. 3 °C/s max. Liquidus temperature (T<sub>L</sub>) 183 °C 217 °C Time (t<sub>L</sub>) maintained above T<sub>L</sub> 60 s to 150 s 60 s to 150 s Peak package body temperature (Tp) Depends on type and case - see table below Time (t<sub>p</sub>)\* within 5 °C of the specified 20 s 30 s classification temperature (T<sub>c</sub>) Ramp-down Ramp-down rate $(T_p \text{ to } T_L)$ 6 °C/s max. 6 °C/s max.

TVDF / 040F 00DF	PEAK PACKAGE BOD	PEAK PACKAGE BODY TEMPERATURE (Tp)		
TYPE / CASE CODE	SnPb EUTECTIC PROCESS	LEAD (Pb)-FREE PROCESS		
591D / 592D - all cases, except X25H, M and R cases	235 °C	260 °C		
591D / 592D - X25H, M and R cases	220 °C	250 °C		
594D / 595D - all cases except C, D, and R	235 °C	260 °C		
594D / 595D - C, D, and R case	220 °C	250 °C		
T95 A, B, S, V, X, Y cases	235 °C	260 °C		
T95 C, D, R, and Z cases	220 °C	250 °C		
14002 B case	235 °C	n/a		
14002 C, D, and R cases	220 °C	n/a		
T96 R case	220 °C	250 °C		
195D all cases, except G, H, R, and Z	235 °C	260 °C		
195D G, H, R, and Z cases	220 °C	250 °C		
695D all cases, except G and H cases	235 °C	260 °C		
695D G, H cases	220 °C	250 °C		
597D, T97, T98 all cases, except V case	220 °C	250 °C		
597D, T97, T98 V case	235 °C	260 °C		
194D all cases, except H and G cases	235 °C	260 °C		
194D H and G cases	220 °C	250 °C		

6 min max.

## Vishay Sprague

#### **GUIDE TO APPLICATION**

 AC Ripple Current: the maximum allowable ripple current shall be determined from the formula:

$$I_{RMS} = \sqrt{\frac{P}{R_{ESR}}}$$

where,

P = power dissipation in W at +25 °C as given in the tables in the product datasheets (Power Dissipation).

R<sub>ESR</sub> = the capacitor equivalent series resistance at the specified frequency

2. **AC Ripple Voltage:** the maximum allowable ripple voltage shall be determined from the formula:

$$V_{RMS} = I_{RMS} \times Z$$

or, from the formula:

$$V_{RMS} = Z \sqrt{\frac{P}{R_{ESR}}}$$

where,

P = power dissipation in W at +25 °C as given in the tables in the product datasheets (Power Dissipation).

R<sub>ESR</sub> = the capacitor equivalent series resistance at the specified frequency

Z = the capacitor impedance at the specified frequency

- 2.1 The sum of the peak AC voltage plus the applied DC voltage shall not exceed the DC voltage rating of the capacitor.
- 2.2 The sum of the negative peak AC voltage plus the applied DC voltage shall not allow a voltage reversal exceeding 10 % of the DC working voltage at +25 °C.
- 3. **Reverse Voltage:** solid tantalum capacitors are not intended for use with reverse voltage applied. However, they have been shown to be capable of withstanding momentary reverse voltage peaks of up to 10 % of the DC rating at 25 °C and 5 % of the DC rating at +85 °C.
- 4. **Temperature Derating:** if these capacitors are to be operated at temperatures above +25 °C, the permissible RMS ripple current shall be calculated using the derating factors as shown:

TEMPERATURE	DERATING FACTOR
+25 °C	1.0
+85 °C	0.9
+125 °C	0.4

5. Power Dissipation: power dissipation will be affected by the heat sinking capability of the mounting surface. Non-sinusoidal ripple current may produce heating effects which differ from those shown. It is important that the equivalent I<sub>RMS</sub> value be established when calculating permissible operating levels. (Power dissipation calculated using derating factor (see paragraph 4)).

#### 6. Attachment:

- 6.1 **Soldering:** capacitors can be attached by conventional soldering techniques: vapor phase, convection reflow, infrared reflow, and hot plate methods. The soldering profile charts show recommended time / temperature conditions for soldering. Preheating is recommended. The recommended maximum ramp rate is 3 °C per second. Attachment with a soldering iron is not recommended due to the difficulty of controlling temperature and time at temperature. The soldering iron must never come in contact with the capacitor. For details see <a href="https://www.vishay.com/doc?40214">www.vishay.com/doc?40214</a>.
- Recommended Mounting Pad Geometries: the nib
  must have sufficient clearance to avoid electrical
  contact with other components. The width
  dimension indicated is the same as the maximum
  width of the capacitor. This is to minimize lateral
  movement.
- 8. Cleaning (Flux Removal) After Soldering:

  TANTAMOUNT<sup>TM</sup> capacitors are compatible with all commonly used solvents such as TES, TMS, Prelete, Chlorethane, Terpene and aqueous cleaning media. However, CFC / ODS products are not used in the production of these devices and are not recommended. Solvents containing methylene chloride or other epoxy solvents should be avoided since these will attack the epoxy encapsulation material.



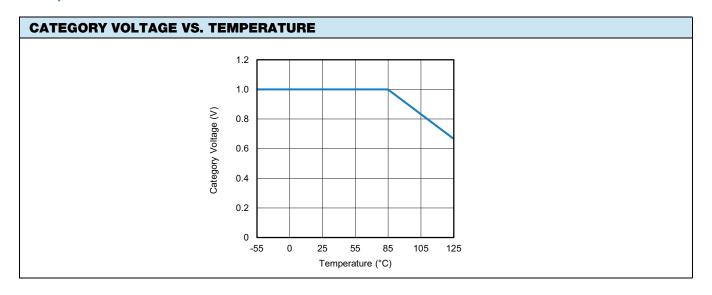
# **COTS Tantalum Capacitors**

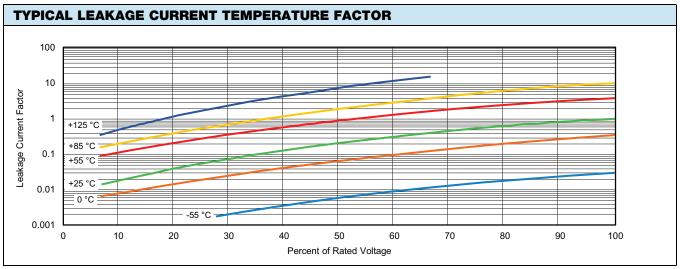
ELECTRICAL PERFORMANCE CHARACTERISTICS					
ITEM	PERFORMANCE CHARACTERISTICS				
Category temperature range	-55 °C to +85 °C (to +125 °C with voltage derating)				
Capacitance tolerance	± 20 %, ± 10 %, tested via bridge method, at 25 °C, 120 Hz				
Dissipation factor	Limit per Standard Ratin	gs table. Tested via bridge	method, at 25 °C, 120 Hz		
ESR	Limit per Standard Ratin	gs table. Tested via bridge	method, at 25 °C, 100 kHz		
Leakage current	After application of rated voltage applied to capacitors for 5 min using a steady source of power with 1 kΩ resistor in series with the capacitor under test, leakage current at 25 °C is not more than 0.01 CV or 0.5 μA, whichever is greater. Note that the leakage current varies with temperature and applied voltage. See graph below for the appropriate adjustment factor.				
Capacitance change by temperature	+15 % max. (at +125 °C) +10 % max. (at +85 °C) -10 % max. (at -55 °C)				
Reverse voltage	Capacitors are capable of withstanding peak voltages in the reverse direction equal to: 10 % of the DC rating at +25 °C 5 % of the DC rating at +85 °C 1 % of the DC rating at +125 °C Vishay does not recommend intentional or repetitive application of reverse voltage.				
Ripple current	For maximum ripple current values (at 25 °C) refer to relevant datasheet. If capacitors are to be used at temperatures above +25 °C, the permissible RMS ripple current (or voltage) shall be calculated using the derating factors:  1.0 at +25 °C  0.9 at +85 °C  0.4 at +125 °C				
Maximum operating and surge	+85	5 °C	+125 °C		
voltages vs. temperature	RATED VOLTAGE (V)	SURGE VOLTAGE (V)	CATEGORY VOLTAGE (V)	SURGE VOLTAGE (V)	
	4.0	5.2	2.7	3.4	
	6.3	8.0	4.0	5.0	
	10	13	7.0	8.0	
	16	20	10	12	
	20	26	13	16	
	25	32	17	20	
	35	46	23	28	
	40	52	26	31	
	50	65	33	40	
	50 <sup>(1)</sup>	60	33	40	
	63	75	42	50	
	75	75	50	50	
Recommended voltage	VOLTAGE RAIL (V)		CAPACITOR VOLTAGE RATING (V)		
derating guidelines	≤ 3.3		6.3		
(below 85 °C) (2)	5		10		
	10		20		
	12		25		
	15		35		
	24		50 or series configuration		
	28		63 or series configuration		
		32	75 or series of		
		OL.	10 01 361163 0	orniguration	

- All information presented in this document reflects typical performance characteristics
- For more information about recommended voltage derating see: <a href="www.vishay.com/doc?40246">www.vishay.com/doc?40246</a>
- (1) Capacitance value 15 µF and higher

<sup>(2)</sup> For temperatures above +85 °C the same voltage derating ratio is recommended, but with respect to category voltage: up to +85 °C: category voltage = rated voltage; at +125 °C: category voltage = 2/3 of rated voltage, between these temperatures it decreases linearly see graph below

Vishay Sprague





- At +25 °C, the leakage current shall not exceed the value listed in the Standard Ratings table.
- At +85 °C, the leakage current shall not exceed 10 times the value listed in the Standard Ratings table.
- At +125 °C, the leakage current shall not exceed 12 times the value listed in the Standard Ratings table

# **Typical Performance Characteristics**

Vishay Sprague

ENVIRONMENT	ENVIRONMENTAL PERFORMANCE CHARACTERISTICS				
ITEM	CONDITION	POST TEST PERFOR	MANCE		
Surge voltage	MIL-PRF-55365 1000 successive test cycles at 85 °C of surge voltage (as specified in the table above), in series with a 33 $\Omega$ resistor at the rate of 30 s ON, 30 s OFF	Capacitance change Dissipation factor Leakage current	Within ± 10 % of initial value Initial specified limit Initial specified limit		
Life test at +85 °C	MIL-STD-202, method 108 1000 h application of rated voltage at 85 °C	Capacitance change Dissipation factor Leakage current	Within ± 10 % of initial value Initial specified limit Shall not exceed 125 % of initial limit		
Life test at +125 °C	MIL-STD-202, method 108 1000 h application 2/3 of rated voltage at 125 °C	Capacitance change Dissipation factor Leakage current	Within ± 10 % of initial value Initial specified limit Shall not exceed 125 % of initial limit		
Moisture resistance	MIL-STD-202, method 106, 20 cycles	Capacitance change Dissipation factor Leakage current	Within ± 15 % of initial value Shall not exceed 150 % of initial limit Shall not exceed 200 % of initial limit		
Stability at low and high temperatures	MIL-PRF-55365	Delta cap limit at 125 °	itial specified value		
Thermal shock	MIL-STD-202, method 107 At -55 °C / +125 °C, for 5 cycles, 30 min at each temperature	Capacitance change Dissipation factor Leakage current	Within ± 10 % of initial value Initial specified limit Initial specified limit		

MECHANICAL I	PERFORMANCE CHARACTERISTICS	
ITEM	CONDITION	POST TEST PERFORMANCE
Terminal strength / Shear force test	Apply a pressure load of 5 N for 10 s ± 1 s horizontally to the center of capacitor side body	Capacitance change Within ± 10 % of initial value Dissipation factor Initial specified limit Leakage current Initial specified limit
		There shall be no mechanical or visual damage to capacitors post-conditioning.
Vibration	MIL-STD-202, method 204, condition D, 10 Hz to 2000 Hz, 20 g peak, 8 h, at rated voltage	Electrical measurements are not applicable, since the same parts are used for shock (specified pulse) test.
		There shall be no mechanical or visual damage to capacitors post-conditioning.
Shock (specified pulse)	MIL-STD-202, method 213, condition I, 100 $g$ peak	Capacitance change Within ± 10 % of initial value Dissipation factor Initial specified limit Leakage current Initial specified limit
		There shall be no mechanical or visual damage to capacitors post-conditioning.
Resistance to soldering heat	MIL-STD-202, method 210, condition J (leadbearing capacitors) and K (lead (Pb)-free capacitors), one heat cycle	Capacitance change Within ± 10 % of initial value Dissipation factor Initial specified limit Leakage current Initial specified limit
Solderability	MIL-STD-202, method 208, ANSI/J-STD-002, test B (leadbearing) and B1 (lead (Pb)-free).	Solder coating of all capacitors shall meet specified requirements.
	Preconditioning per category C (category E - optional).  Does not apply to gold terminations.  Lead (Pb)-free and leadbearing capacitors are backward and forward compatible	There shall be no mechanical or visual damage to capacitors post-conditioning.
Resistance to solvents	MIL-STD-202, method 215	There shall be no mechanical or visual damage to capacitors post-conditioning. Body marking shall remain legible.
Flammability	Encapsulation materials meet UL 94 V-0 with an oxygen index of 32 %	



## **Legal Disclaimer Notice**

Vishay

#### **Disclaimer**

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.